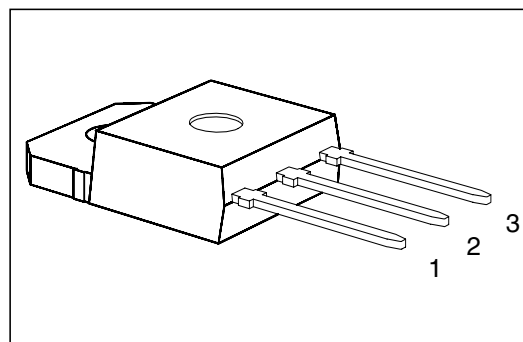


Features

- N channel
- Enhancement mode
- Temperature sensor with thyristor characteristic
- The drain pin is electrically shorted to the tab
- AEC qualified
- Green product (RoHS compliant)



Pin	1	2	3
	G	D	S

Type	V_{DS}	I_D	$R_{DS(on)}$	Package	
BTS 240A	50 V	58 A	0.018 Ω	PG-TO-218	

Maximum Ratings

Parameter	Symbol	Values	Unit
Drain-source voltage	V_{DS}	50	V
Drain-gate voltage, $R_{GS} = 20 \text{ k}\Omega$	V_{DGR}	50	
Gate-source voltage	V_{GS}	± 20	
Continuous drain current, $T_C = 73 \text{ }^\circ\text{C}$	I_D	58	A
ISO drain current $T_C = 85 \text{ }^\circ\text{C}$, $V_{GS} = 10 \text{ V}$, $V_{DS} = 0.5 \text{ V}$	I_{D-ISO}	21.0	
Pulsed drain current, $T_C = 25 \text{ }^\circ\text{C}$	$I_{D \text{ puls}}$	232	
Short circuit current, $T_j = -55 \dots +150 \text{ }^\circ\text{C}$	I_{SC}	147	
Short circuit dissipation, $T_j = -55 \dots +150 \text{ }^\circ\text{C}$	P_{SCmax}	2200	W
Power dissipation	P_{tot}	170	
Operating and storage temperature range	T_j, T_{stg}	$-55 \dots +150$	$^\circ\text{C}$
Thermal resistance			K/W
Chip-case	$R_{th \text{ JC}}$	≤ 0.74	
Chip-ambient	$R_{th \text{ JA}}$	≤ 45	

Electrical Characteristics

at $T_j = 25\text{ °C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

Static Characteristics

Drain-source breakdown voltage $V_{GS} = 0, I_D = 0.25\text{ mA}$	$V_{(BR)DSS}$	50	–	–	V
Gate threshold voltage $V_{GS} = V_{DS}, I_D = 1\text{ mA}$	$V_{GS(th)}$	2.5	3.0	3.5	
Zero gate voltage drain current $V_{GS} = 0\text{ V}, V_{DS} = 50\text{ V}$ $T_j = 25\text{ °C}$ $T_j = 125\text{ °C}$	I_{DSS}	– –	0.1 10	1.0 100	μA
Gate-source leakage current $V_{GS} = 20\text{ V}, V_{DS} = 0$ $T_j = 25\text{ °C}$ $T_j = 150\text{ °C}$	I_{GSS}	– –	10 2.0	100 4.0	nA μA
Drain-source on-state resistance $V_{GS} = 10\text{ V}, I_D = 47\text{ A}$	$R_{DS(on)}$	–	0.012	0.018	Ω

Dynamic Characteristics

Forward transconductance $V_{DS} \geq 2 \times I_D \times R_{DS(on)max}, I_D = 47\text{ A}$	g_{fs}	20.0	43.0	–	S
Input capacitance $V_{GS} = 0, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$	C_{iss}	–	2.9	4.3	nF
Output capacitance $V_{GS} = 0, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$	C_{oss}	–	1.4	2.1	
Reverse transfer capacitance $V_{GS} = 0, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$	C_{rss}	–	0.5	0.8	
Turn-on time t_{on} , ($t_{on} = t_{d(on)} + t_r$) $V_{CC} = 30\text{ V}, V_{GS} = 10\text{ V}, I_D = 3\text{ A}, R_{GS} = 50\text{ }\Omega$	$t_{d(on)}$	–	50	75	ns
	t_r	–	150	230	
Turn-off time t_{off} , ($t_{off} = t_{d(off)} + t_f$) $V_{CC} = 30\text{ V}, V_{GS} = 10\text{ V}, I_D = 3\text{ A}, R_{GS} = 50\text{ }\Omega$	$t_{d(off)}$	–	350	560	
	t_f	–	250	330	

Electrical Characteristics (cont'd)
 at $T_j = 25\text{ °C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

Reverse Diode

Continuous source current	I_S	–	–	58	A
Pulsed source current	I_{SM}	–	–	232	
Diode forward on-voltage $I_F = 58\text{ A}$, $V_{GS} = 0$	V_{SD}	–	1.4	1.8	V
Reverse recovery time $I_F = I_S$, $di_F/dt = 100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	t_{rr}	–	100	–	ns
Reverse recovery charge $I_F = I_S$, $di_F/dt = 100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	Q_{rr}	–	0.3	–	μC

Temperature Sensor

Forward voltage $I_{TS(on)} = 10\text{ mA}$, $T_j = -55 \dots +150\text{ °C}$ Sensor override, $t_p \leq 100\text{ }\mu\text{s}$ $T_j = -55 \dots +160\text{ °C}$	$V_{TS(on)}$	0.7 –	1.4 –	1.5 10	V
Forward current $T_j = -55 \dots +150\text{ °C}$ Sensor override, $t_p \leq 100\text{ }\mu\text{s}$ $T_j = -55 \dots +160\text{ °C}$	$I_{TS(on)}$	– –	– –	10 600	mA
Holding current, $V_{TS(off)} = 5\text{ V}$, $T_j = 25\text{ °C}$ $T_j = 150\text{ °C}$	I_H	0.05 0.05	0.1 0.2	0.5 0.3	
Switching temperature $V_{TS} = 5\text{ V}$	$T_{TS(on)}$	150	–	–	°C
Turn-off time $V_{TS} = 5\text{ V}$, $I_{TS(on)} = 2\text{ mA}$	t_{off}	0.5	–	2.5	μs

Examples for short-circuit protection

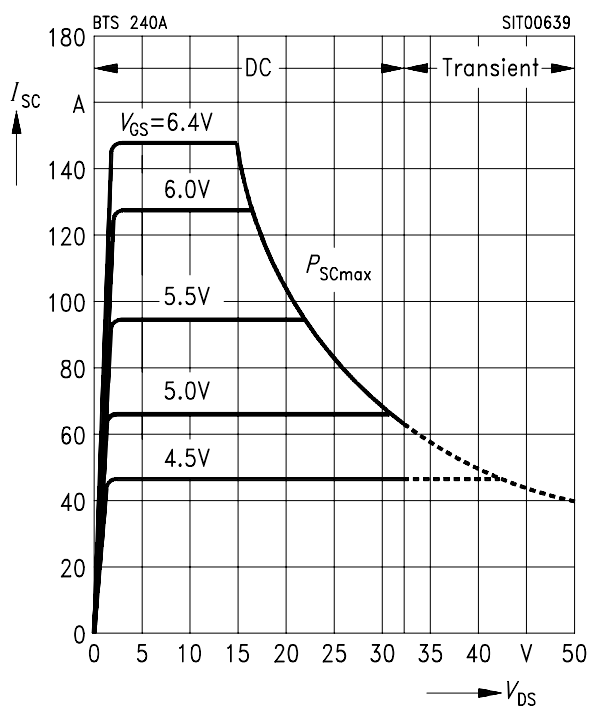
at $T_j = -55 \dots +150 \text{ }^\circ\text{C}$, unless otherwise specified.

Parameter	Symbol	Examples			Unit
		1	2	–	
Drain-source voltage	V_{DS}	15	30	–	V
Gate-source voltage	V_{GS}	6.4	5.1	–	
Short-circuit current	I_{SC}	< 147	< 67	–	A
Short-circuit dissipation	P_{SC}	< 2200	< 2000	–	W
Response time $T_j = 25 \text{ }^\circ\text{C}$, before short circuit	$t_{SC(off)}$	< 25	< 25	–	ms

Short-circuit protection $I_{SC} = f(V_{DS})$

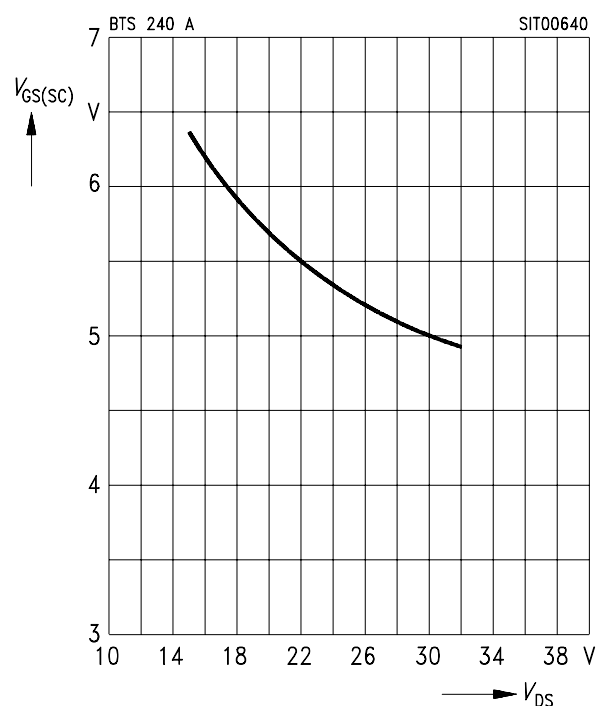
Parameter: V_{GS}

Diagram to determine I_{SC} for $T_j = -55 \dots +150 \text{ }^\circ\text{C}$

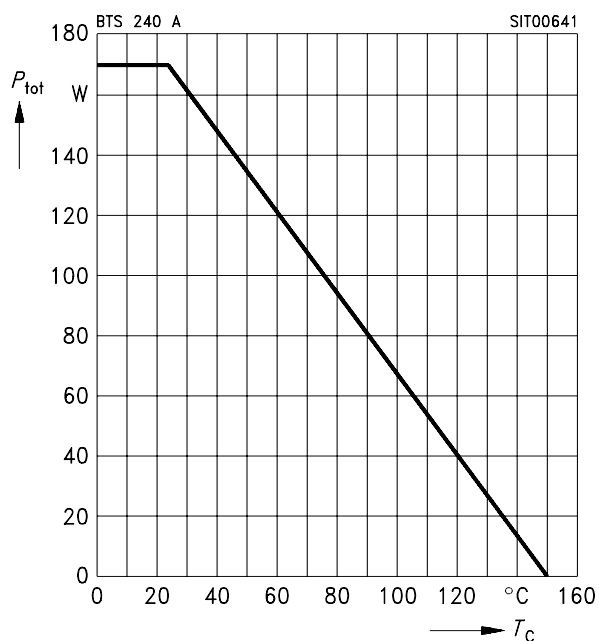


Max. gate voltage $V_{GS(SC)} = f(V_{DS})$

Parameter: $T_j = -55 \dots +150 \text{ }^\circ\text{C}$

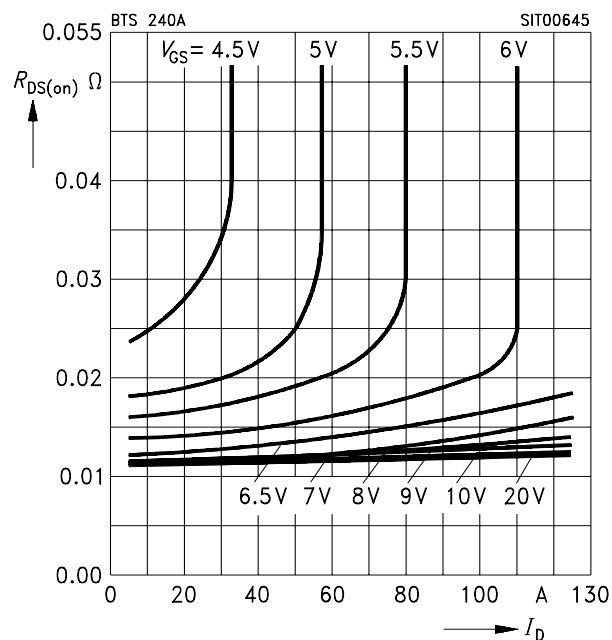


Max. power dissipation $P_{\text{tot}} = f(T_C)$



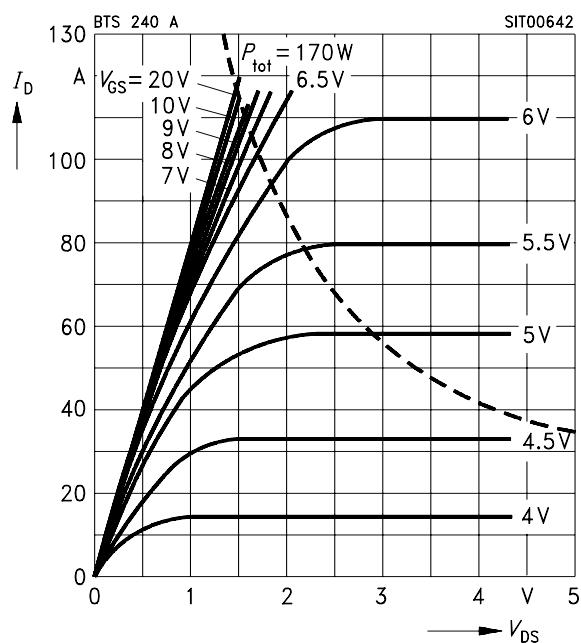
Typ. drain-source on-state resistance $R_{\text{DS(on)}} = f(I_D)$

Parameter: V_{GS}



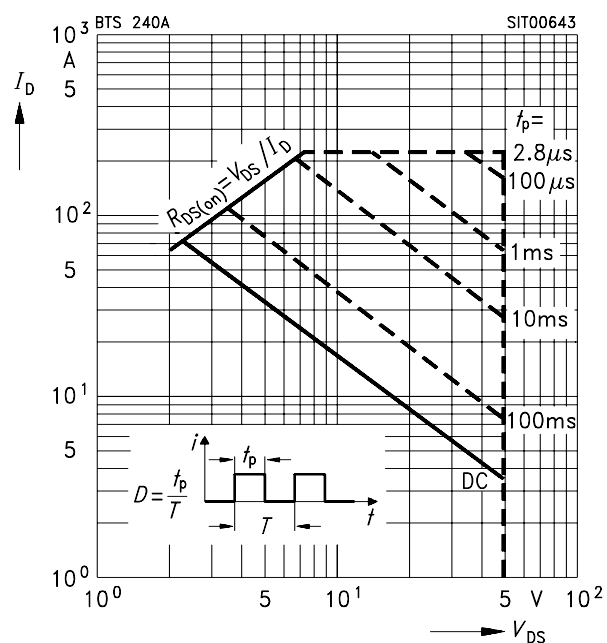
Typical output characteristics $I_D = f(V_{\text{DS}})$

Parameter: $t_p = 80 \mu\text{s}$



Safe operating area $I_D = f(V_{\text{DS}})$

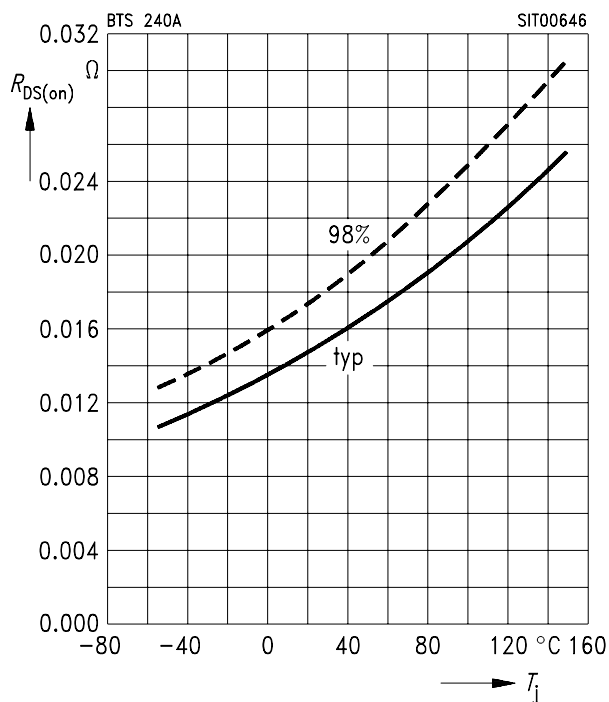
Parameter: $D = 0.01$, $T_C = 25^\circ\text{C}$



Drain-source on-state resistance

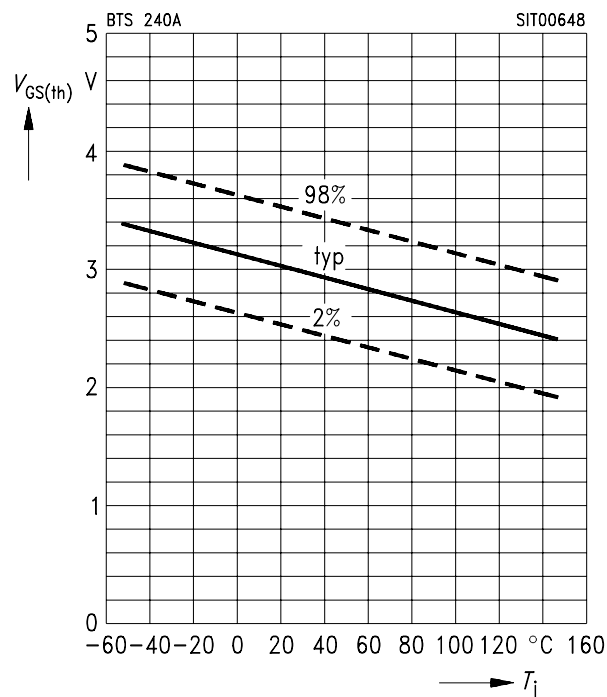
$$R_{DS(on)} = f(T_j)$$

Parameter: $I_D = 47\text{ A}$, $V_{GS} = 10\text{ V}$ (spread)



Gate threshold voltage $V_{GS(th)} = f(T_j)$

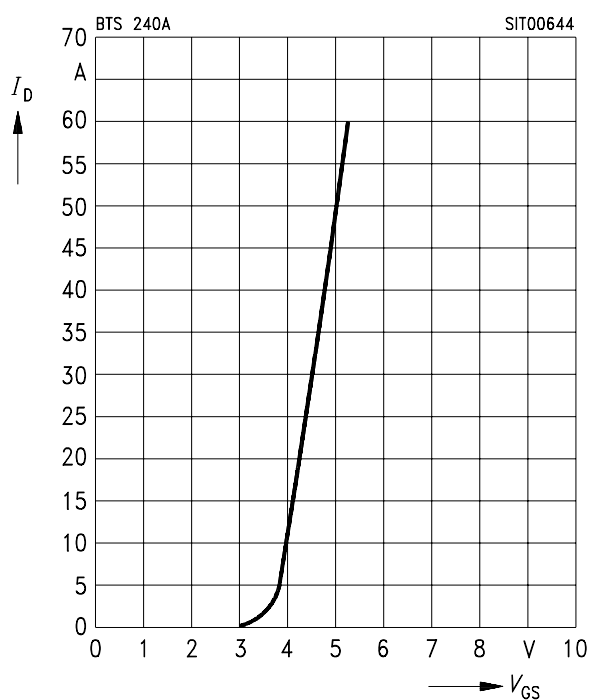
Parameter: $V_{DS} = V_{GS}$, $I_D = 1\text{ mA}$



Typ. transfer characteristic

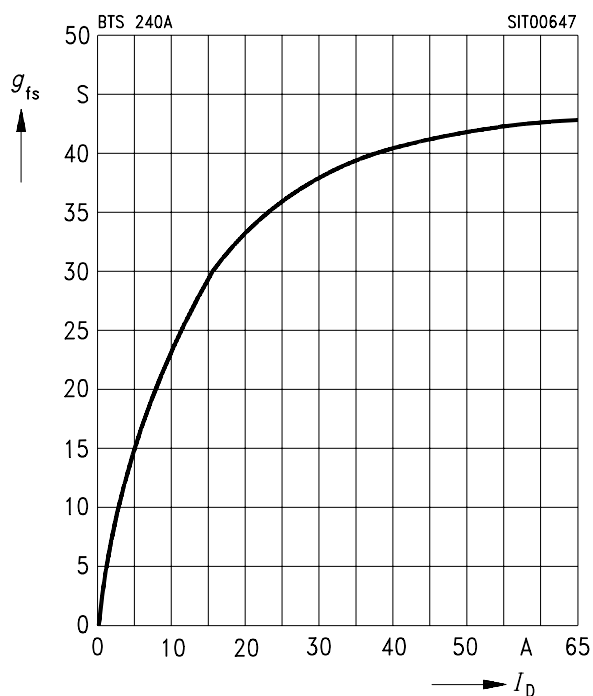
$$I_D = f(V_{GS})$$

Parameter: $t_p = 80\text{ }\mu\text{s}$, $V_{DS} = 25\text{ V}$



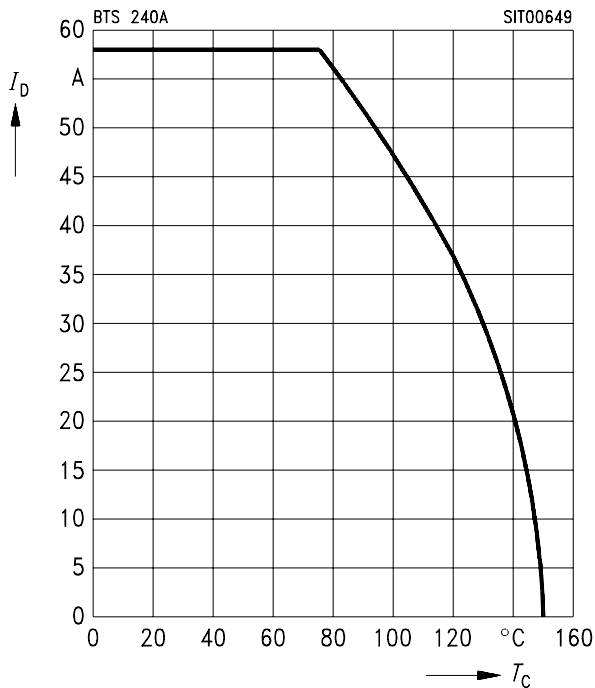
Typ. transconductance $g_{fs} = f(I_D)$

Parameter: $t_p = 80\text{ }\mu\text{s}$, $V_{DS} = 25\text{ V}$



Continuous drain current $I_D = f(T_C)$

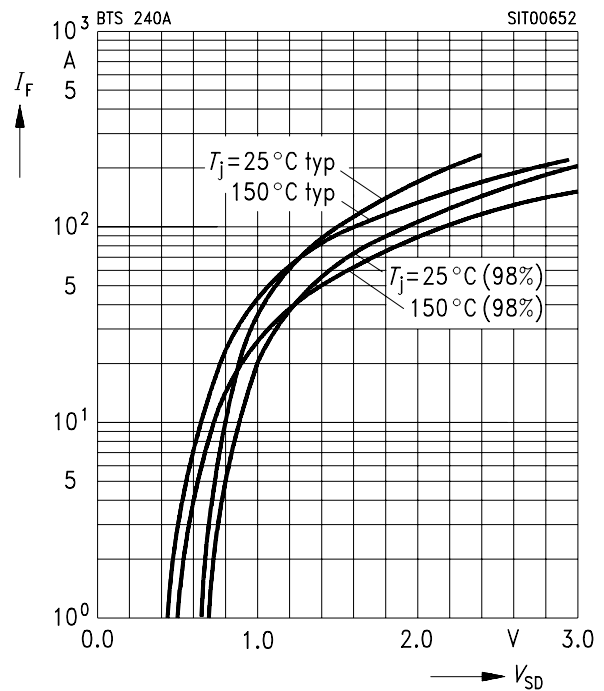
Parameter: $V_{GS} \geq 10 \text{ V}$



Forward characteristics of reverse diode

$I_F = f(V_{SD})$

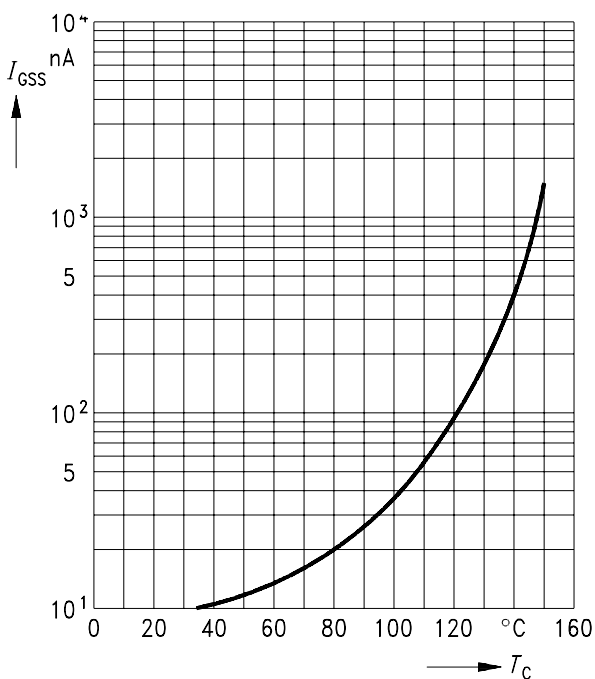
Parameter: $T_j, t_p = 80 \mu\text{s}$ (spread)



Typ. gate-source leakage current

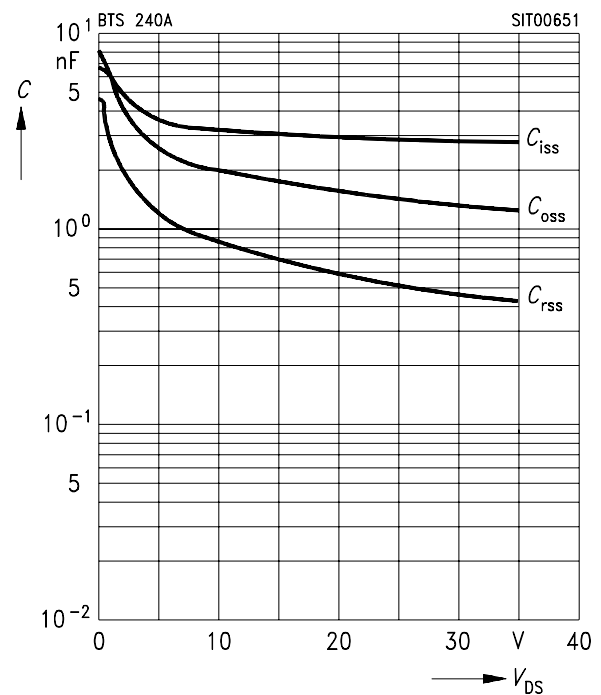
$I_{GSS} = f(T_C)$

Parameter: $V_{GS} = 20 \text{ V}, V_{DS} = 0$



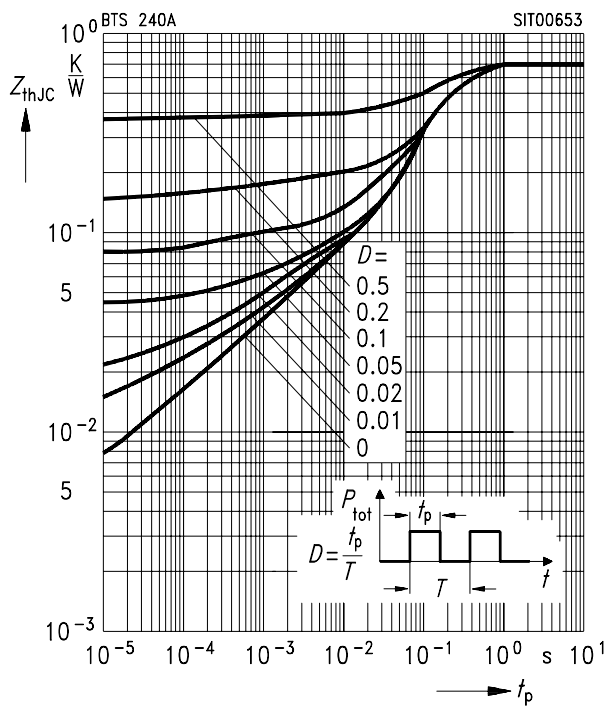
Typ. capacitances $C = f(V_{DS})$

Parameter: $V_{GS} = 0, f = 1 \text{ MHz}$



Transient thermal impedance $Z_{thJC} = f(t_p)$

Parameter: $D = t_p/T$



1 Package Outlines

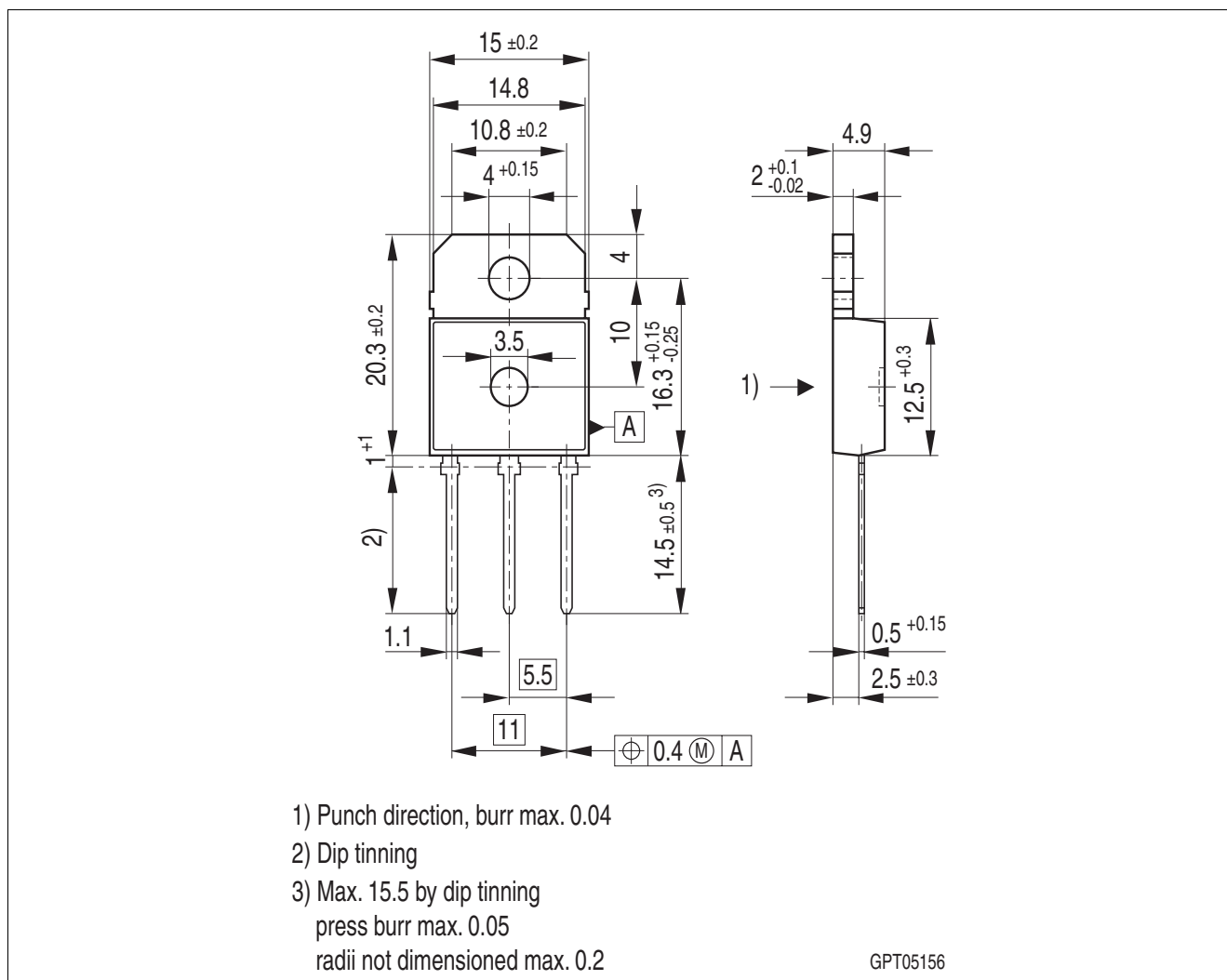


Figure 1 PG-T0218-3

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

2 Revision History

Version	Date	Changes
Rev. 1.2	2010-07-12	initial released version of RoHS compliant derivative of BTS240A Page 1 and 9: added RoHS compliance statement and Green product feature Page 1 and 9: Package changed to RoHS compliant version Page 1: removed Package parameter (humidity and climatic) Page 10: added Revision history Page 11: updated Disclaimer

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